

10/591352
IAP9 Rec'd PCT/PTO 31 AUG 2006

INFORMATION DISCLOSURE STATEMENT TRANSMITTAL	<table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 60%;">Application Number</td> <td></td> </tr> <tr> <td>Filing Date</td> <td></td> </tr> <tr> <td>First Named Inventor</td> <td>KOOPS, GERRIT, E., J.</td> </tr> <tr> <td>Group Art Unit</td> <td></td> </tr> <tr> <td>Examiner Name</td> <td></td> </tr> <tr> <td>Atty. Docket Number</td> <td>GB04 0056US1</td> </tr> </table>	Application Number		Filing Date		First Named Inventor	KOOPS, GERRIT, E., J.	Group Art Unit		Examiner Name		Atty. Docket Number	GB04 0056US1
Application Number													
Filing Date													
First Named Inventor	KOOPS, GERRIT, E., J.												
Group Art Unit													
Examiner Name													
Atty. Docket Number	GB04 0056US1												

To Commissioner For Patents
Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number No.-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
	1	US- 5 637 898	06/10/1997	BALIGA BANTVAL J.	
		US-			
		US-			
		US-			
		US-			
		US-			

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number (ctry ³ -no.-kind ⁵ , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear T ⁶
	1	WO 01/09956	02/08/2001	LARIK, JOOST ET AL.	

NON-PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶
	1	LIN M-J ET AL: "CHARACTERIZING TRENCH-GATE POWER METAL-OXIDE-SEMICONDUCTOR FIELD EFFECT TRANSISTOR WITH MULTI-LAYER DIELECTRICS AT THE TRENCH BOTTOM"; JAPANESE JOURNAL OF APPLIED PHYSICS, PART 1; VOL. 42 NO. 11; NOV. 2003; TOKOYO JP PP 6795-6799.	

Examiner Signature	Date Considered
---------------------------	------------------------

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the